

S34MS02G200BHI003

S34MS02G200BHI003 Information

(A) Heisener.com

For Reference Only

Part NumberS34MS02G200BHI003ManufacturerCypress Semiconductor CorpCategoryIntegrated Circuits (ICs)

Memory

Description NAND

Package -

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









S34MS02G200BHI003 Specifications

	Report errors?
Supplier Device Package	-
Package / Case	-
Mounting Type	-
Operating Temperature	-40°C ~ 85°C (TA)
Voltage - Supply	1.7 V ~ 1.95 V
Access Time	45ns
Write Cycle Time - Word, Page	45ns
Clock Frequency	-
Memory Interface	Parallel
Memory Size	2Gb (256M x 8)
Technology	FLASH - NAND
Memory Format	FLASH
Memory Type	Non-Volatile
Series	MS-2
Package	-
	Memory
Category	Integrated Circuits (ICs)
Manufacturer	Cypress Semiconductor Corp
Manufacturer Part Number	S34MS02G200BHI003

S34MS02G200BHI003 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

S34MS02G200BHI003 Payment Methods









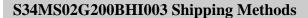
























If you have any question about S34MS02G200BHI003, please do not hesitate to contact us!

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